

New way to move atomically thin semiconductors for use in flexible devices

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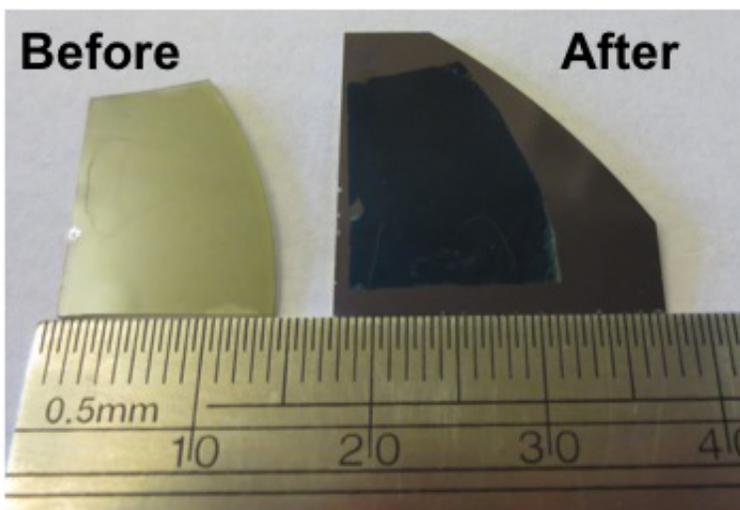


Image of the thin film on the original growth substrate (left) and after being transferred (right). Credit: Linyou Cao.

Researchers from North Carolina State University have developed a new way to transfer thin semiconductor films, which are only one atom thick, onto arbitrary substrates, paving the way for flexible computing or photonic devices. The technique is much faster than existing methods and can perfectly transfer the atomic scale thin films from one substrate to others, without causing any cracks.

At issue are molybdenum sulfide (MoS_2) thin films that are only one atom thick, first developed by Dr. Linyou Cao, an assistant professor of

materials science and engineering at NC State. MoS₂ is an inexpensive semiconductor material with electronic and optical properties similar to materials already used in the semiconductor industry.

"The ultimate goal is to use these atomic-layer semiconducting thin films to create devices that are extremely flexible, but to do that we need to transfer the [thin films](#) from the substrate we used to make it to a flexible substrate," says Cao, who is senior author of a paper on the new transfer technique. "You can't make the thin film on a flexible substrate because [flexible substrates](#) can't withstand the high temperatures you need to make the thin film."

Cao's team makes MoS₂ films that are an atom thick and up to 5 centimeters in diameter. The researchers needed to find a way to move that thin film without wrinkling or cracking it, which is challenging due to the film's extreme delicacy.

"To put that challenge in perspective, an atom-thick thin film that is 5 centimeters wide is equivalent to a piece of paper that is as wide as a large city," Cao said. "Our goal is to transfer that big, thin paper from one city to another without causing any damage or wrinkles."

Existing techniques for transferring such thin [films](#) from a substrate rely on a process called chemical etching, but the chemicals involved in that process can damage or contaminate the film. Cao's team has developed a technique that takes advantage of the MoS₂'s physical properties to transfer the thin film using only room-temperature water, a tissue and a pair of tweezers.

MoS₂ is hydrophobic - it repels water. But the sapphire substrate the thin film is grown on is hydrophilic - it attracts water. Cao's new transfer technique works by applying a drop of water to the thin film and then poking the edge of the film with tweezers or a scalpel so that the water

can begin to penetrate between the MoS₂ and the sapphire. Once it has begun to penetrate, the water pushes into the gap, floating the thin film on top. The researchers use a tissue to soak up the water and then lift the thin film with tweezers and place it on a flexible substrate. The whole process takes a couple of minutes. Chemical etching takes hours.

"The water breaks the adhesion between the substrate and the thin film - but it's important to remove the [water](#) before moving the film," Cao says. "Otherwise, capillary action would cause the film to buckle or fold when you pick it up.

"This new transfer technique gets us one step closer to using MoS₂ to create flexible computers," Cao adds. "We are currently in the process of developing devices that use this technology."

More information: A "just accepted" version of the paper, "Surface Energy-Assisted Perfect Transfer of Centimeter-Scale Monolayer and Fewlayer MoS₂ Films onto Arbitrary Substrates," was published online Oct. 27 in *ACS Nano*. pubs.acs.org/doi/abs/10.1021/nm5057673

Provided by North Carolina State University

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